

SPECIFICATION OF LED CHIP

C570-35V

[Yellow Green]

1) Commodity Type and Physical Characteristics.

- | | | |
|----------------------|------------------------------|-------------------------|
| 1. Material | InGaAlP/GaAs | |
| 2. Electrode | Top Side P (anode) side | : Au Alloy/Au or Al Pad |
| | Bottom Side N (cathode) side | : Au Alloy |
| 3. Electrode Pattern | | Fig.1 |
| 4. Chip Size | | Fig.2 |
| 5. Chip Thickness | | Fig.2 |
| 6. Emission Area | | Fig.2 |

2) Electro-Optical Characteristics [Ta=25°C]

Parameters	Symbol	Condition	Min.	Typ.	Max.	Unit
Forward Voltage	V _f	I _f =20mA		1.9	2.3	V
Reverse Current	I _r	V _r =5V			10	uA
Brightness	I _v	I _f =20mA	15	30		mcd
Power Intensity	P _o	I _f =20mA		0.1		mW
Peak Wavelength	λ _p	I _f =20mA	565	570	575	nm
Spectral Radiation Bandwidth	Δλ	I _f =20mA		15		nm
RiseTime	t _r	I _f =20mA		-		ns
FallTime	t _f	I _f =20mA		-		ns

‡ Die shall be mounted on TO=18 gold header without resin coated.

[Unit : um]

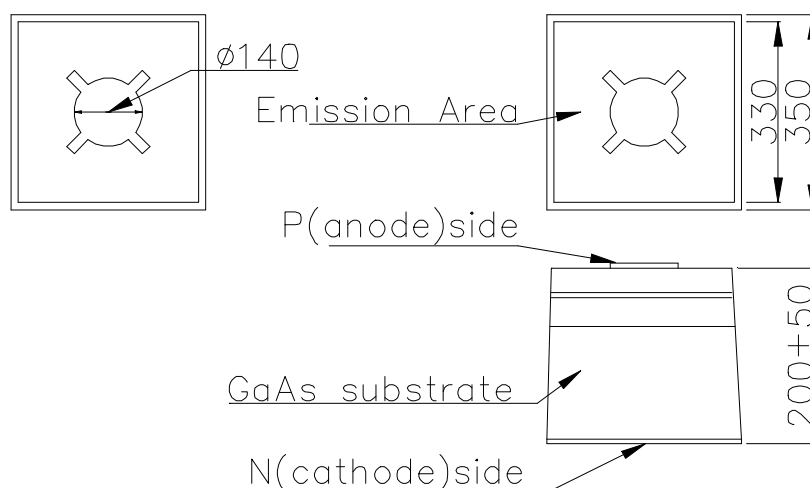


Fig.1 Electrode Pattern

Fig.2 Chip size and Emission Area